

Fuji Discrete Package IGBT

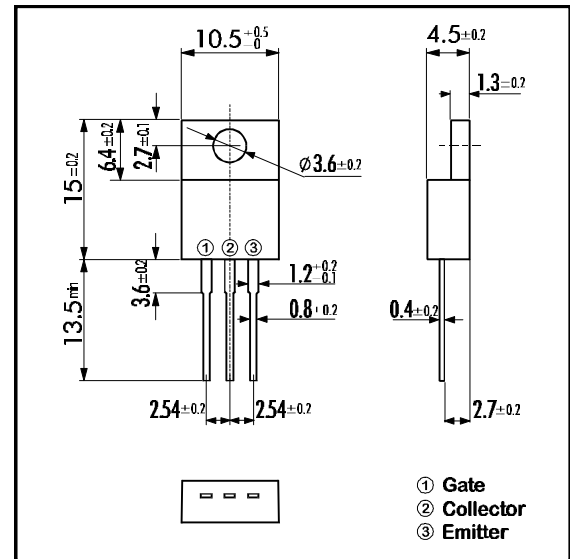
■ Features

- Square RBSOA
- Low Saturation Voltage
- Less Total Power Dissipation
- Minimized Internal Stray Inductance

■ Applications

- High Power Switching
- A.C. Motor Controls
- D.C. Motor Controls
- Uninterruptible Power Supply

■ Outline Drawing

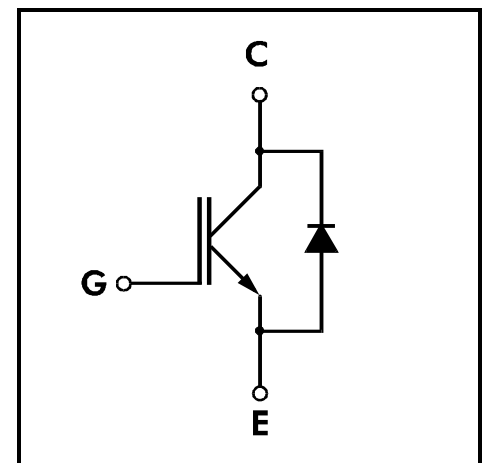


■ Maximum Ratings and Characteristics

• Absolute Maximum Ratings (T_c=25°C)

Items	Symbols	Ratings	Units
Collector-Emitter Voltage	V _{CES}	600	V
Gate -Emitter Voltage	V _{GES}	± 20	V
Collector Current	DC T _c = 25°C	I _{C 25}	20
	DC T _c =100°C	I _{C 100}	10
	1ms T _c = 25°C	I _{C PULSE}	80
IGBT Max. Power Dissipation	P _C	75	W
FWD Max. Power Dissipation	P _C	35	W
Operating Temperature	T _j	+150	°C
Storage Temperature	T _{stg}	-40 ~ +125	°C
Mounting Screw Torque		40	Nm

■ Equivalent Circuit



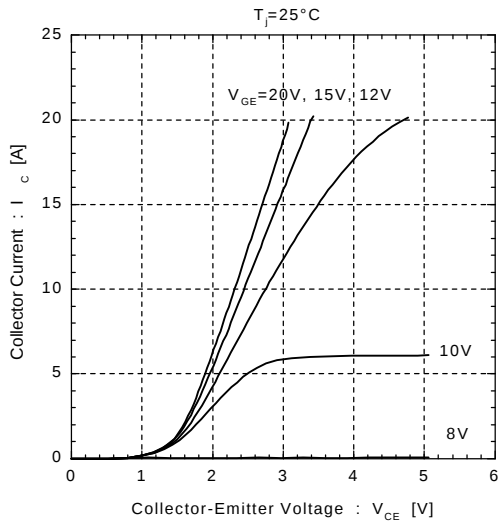
• Electrical Characteristics (at T_j=25°C)

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Zero Gate Voltage Collector Current	I _{CES}	V _{GE} =0V V _{CE} =600V			1.0	mA
Gate-Emitter Leakage Current	I _{GES}	V _{CE} =0V V _{GE} =± 20V			20	μA
Gate-Emitter Threshold Voltage	V _{GE(th)}	V _{GE} =20V I _C =10mA	5.5		8.5	V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	V _{GE} =15V I _C =10A			3.0	V
Input capacitance	C _{ies}	V _{GE} =0V		700		pF
Output capacitance	C _{oes}	V _{CE} =10V		150		
Reverse Transfer capacitance	C _{res}	f=1MHz		20		
Switching Time	Turn-on Time	t _{ON}	V _{CC} =300V		1.2	μs
		t _r	I _C =10A		0.6	
	Turn-off Time	t _{OFF}	V _{GE} =±15V		1.0	
		t _f	R _G =220Ω		0.35	
	Turn-on Time	t _{ON}	V _{CC} =300V	0.16		μs
		t _r	I _C =10A	0.11		
	Turn-off Time	t _{OFF}	V _{GE} =+15V	0.30		
		t _f	R _G =22Ω		0.35	
Diode Forward On-Voltage	V _F	I _F =10A V _{GE} =0V			3.0	V
Reverse Recovery Time	t _{rr}	I _F =10A, V _{GE} =-10V, di/dt=100A/μs			300	ns

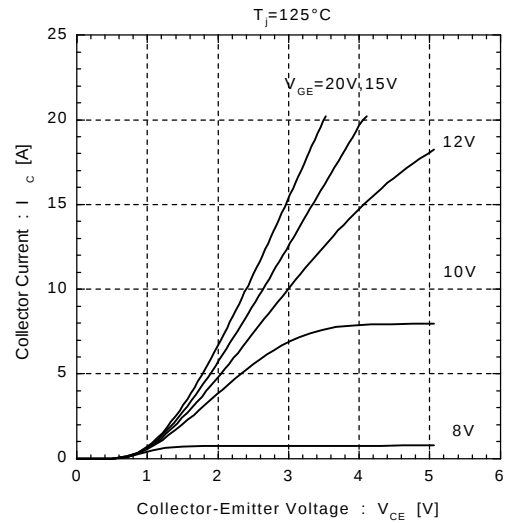
• Thermal Characteristics

Items	Symbols	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance	R _{th(j-c)}	IGBT			1.66	°C/W
	R _{th(j-e)}	Diode			3.57	

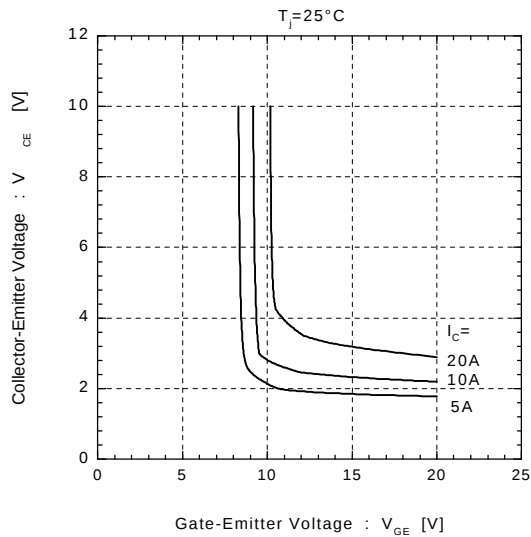
Collector Current vs. Collector-Emitter Voltage



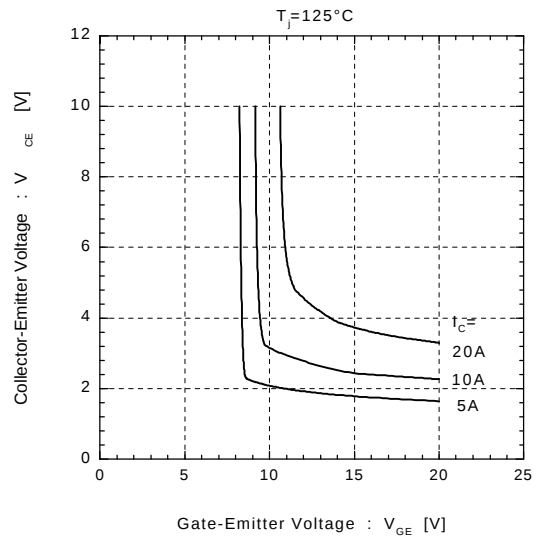
Collector Current vs. Collector-Emitter Voltage



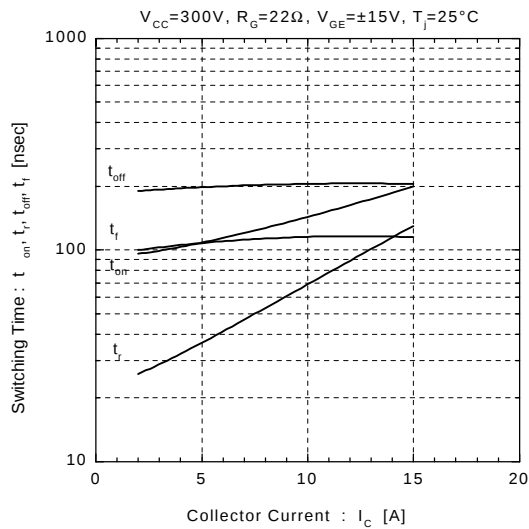
Collector-Emitter Voltage vs. Gate-Emitter Voltage



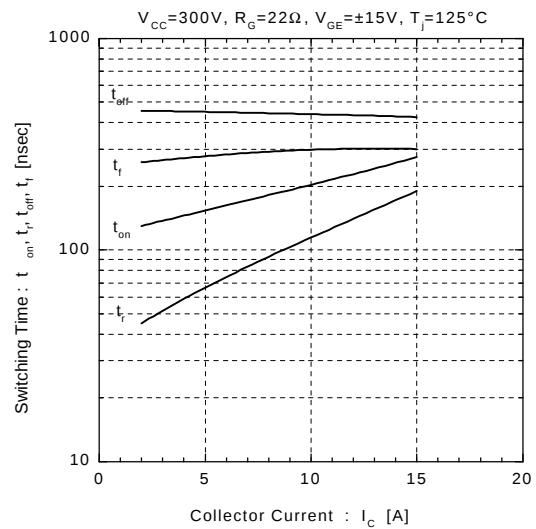
Collector-Emitter Voltage vs. Gate-Emitter Voltage

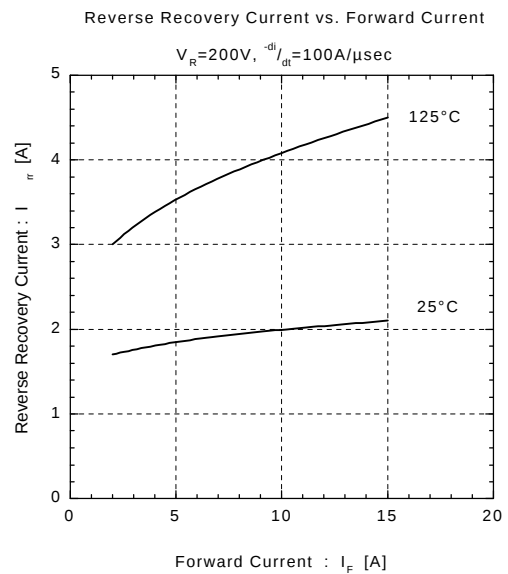
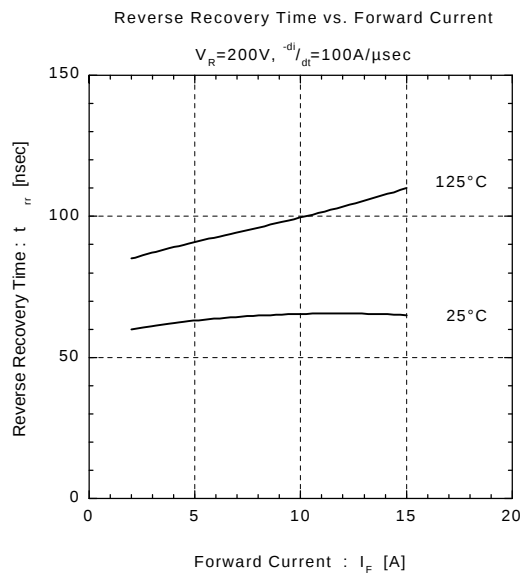
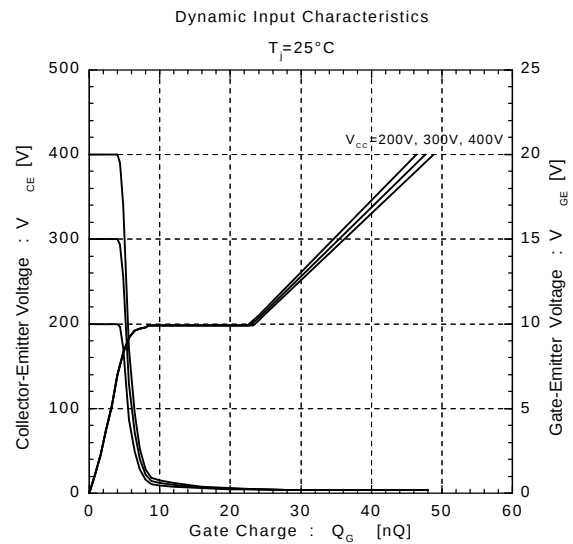
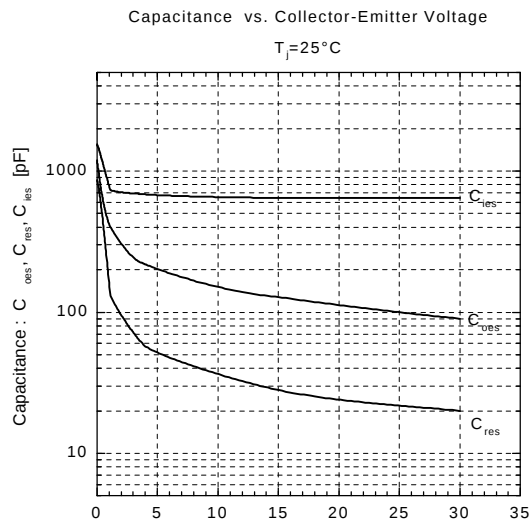
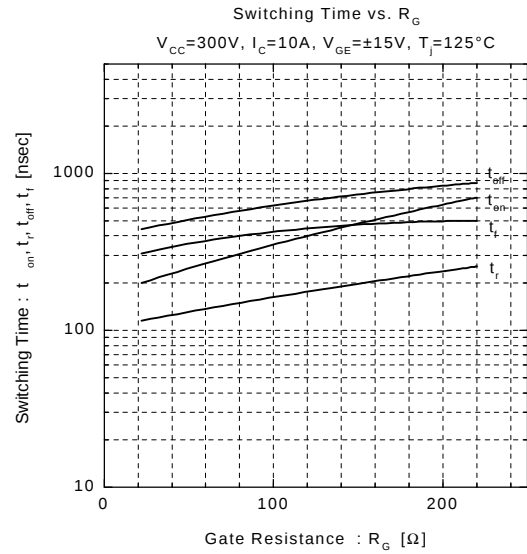
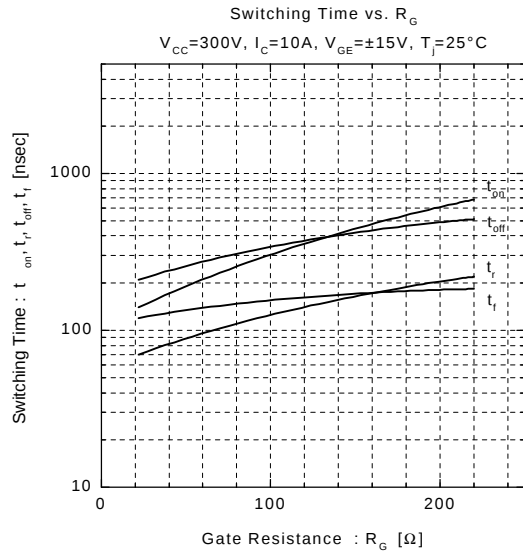


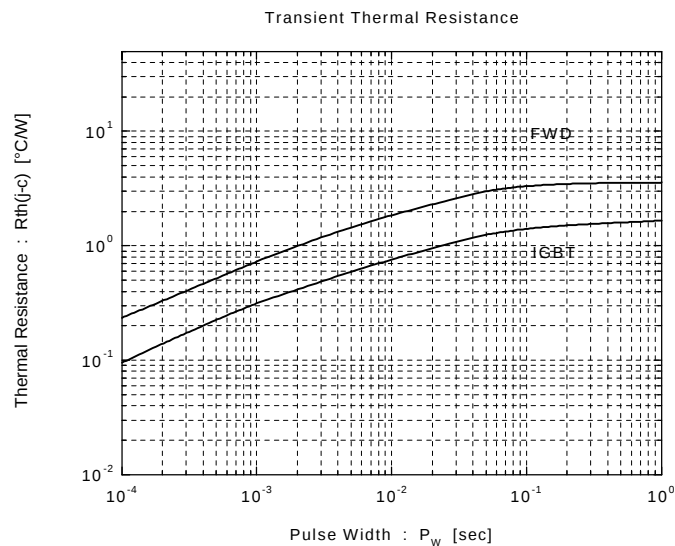
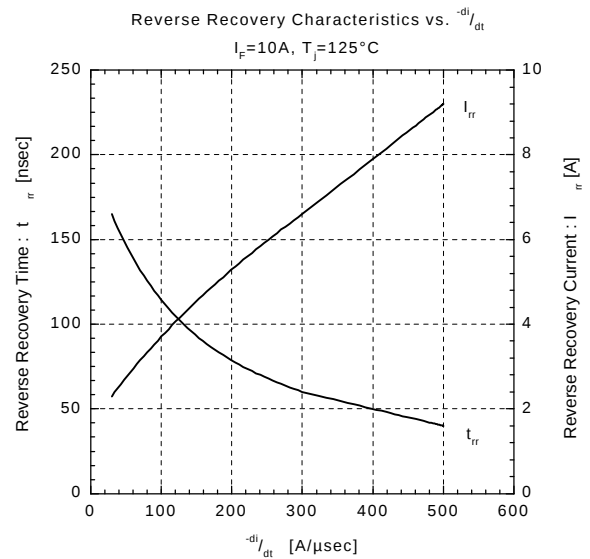
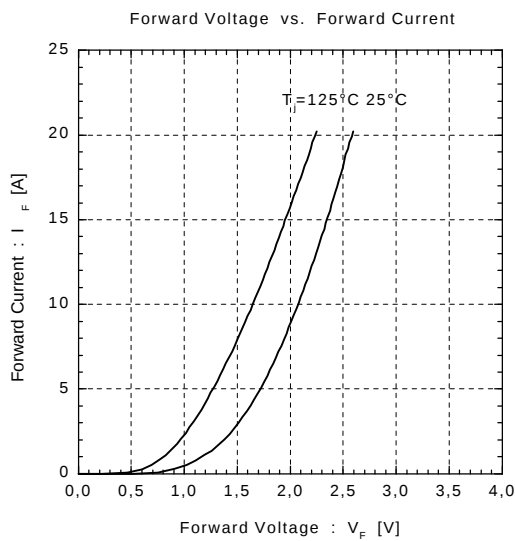
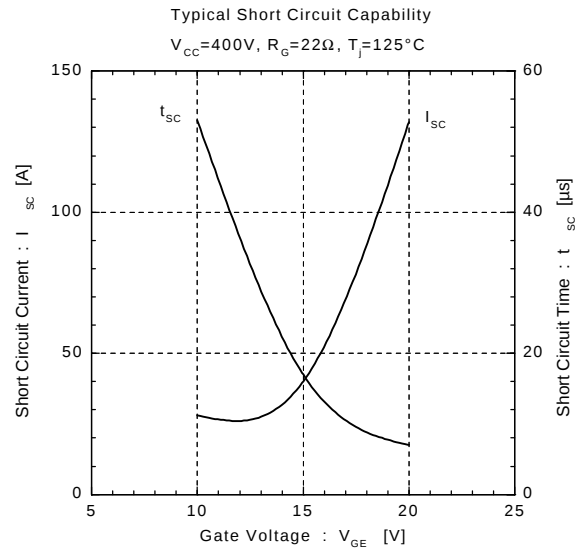
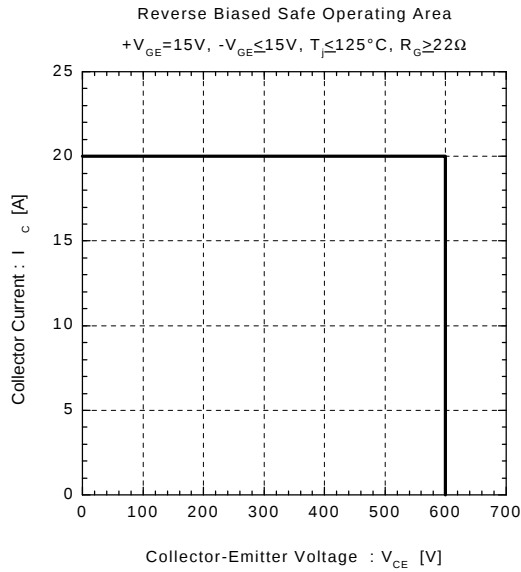
Switching Time vs. Collector Current



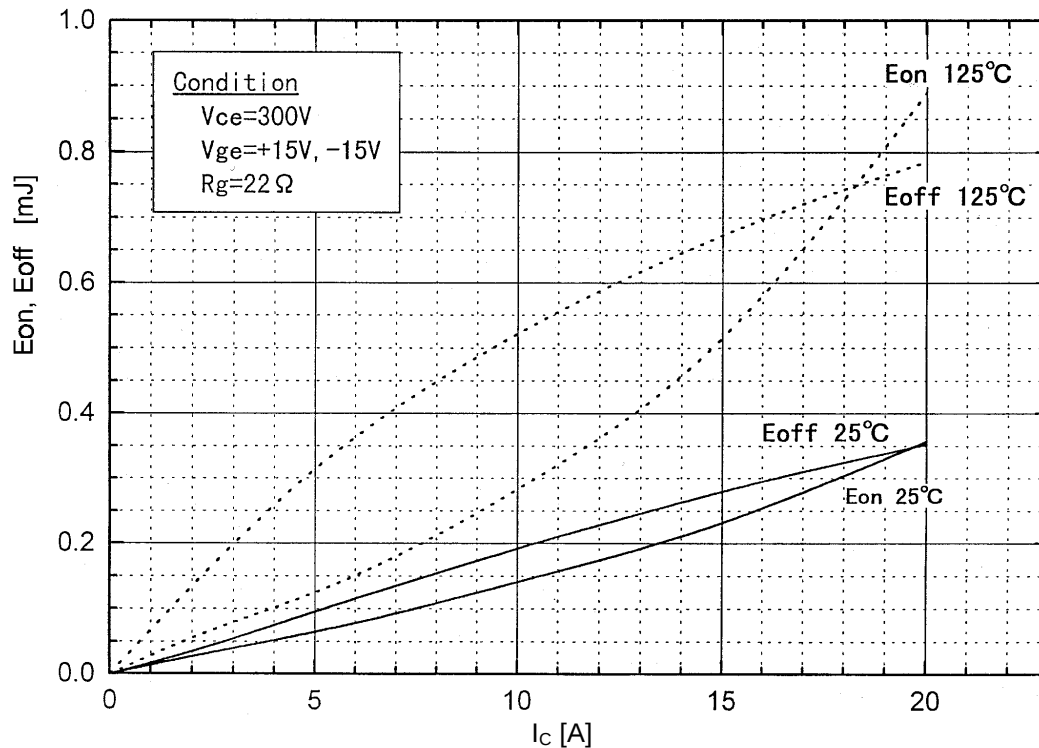
Switching Time vs. Collector Current



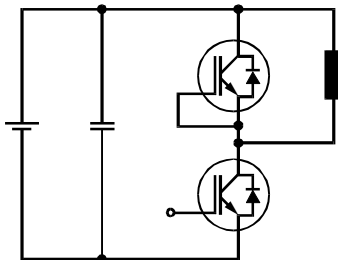




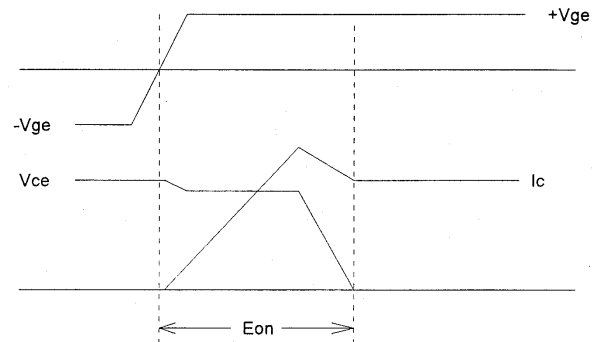
Switching losses (E_{on} , E_{off} vs. I_c)



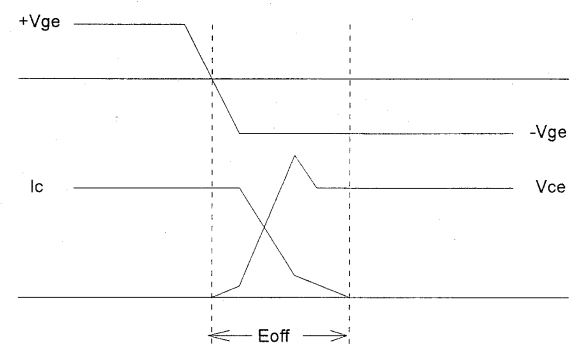
Test Circuit



Switching waveforms



Turn-on Waveforms



Turn-off Waveforms